UNISONIC TECHNOLOGIES CO., LTD

S3515 **CMOS IC**

PC POWER SUPPLY **SUPERVISORS**

DESCRIPTION

The UTC S3515 is specially designed for switching power supply system. It provides over-voltage protection, over-current protection, under-voltage protection, on/off control and power good signal generating.

OVP/UVP (Over/Under-Voltage Protection) monitors 3.3V, 5V and double 12V to protect our power supply and PC, FPO goes to high when one of these supply voltages exceeds their normal operation voltage range.

OCP (Over Current Protection) monitors IS33, IS5, IS12 input current. The voltage difference across external current shunt is used for OCP functions. An external resistor which is connected between the RI pin and the GND pin can be used to adjust protection threshold. To achieve better immunity for lighting surge glitch and to prevent accidental power shut down during dynamic loading condition, the de-bounce time for UVP/OCP is 73us respectively. The deglitch time for OVP is 73uS for better noise immunity.

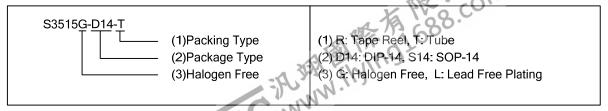
The power supply is turned on after 38mS de-bounce time when PSON signal is set from high to low. To turn off power supply, PSON signal is set from low to high and the de-bounce time is 115mS. When PGI input voltage level is lower than the internal 1.15V reference voltage, after 73uS de-bounce time, the PGO signal is pulled low.

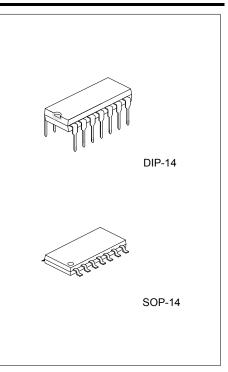


- * Over/Under-Voltage Protection for 3.3V, 5V, and Two 12V
- * Over-Current Protection for 3.3V, 5V, and Two 12V
- * PGO and FPO pins with Open Drain Output Stage
- * 300mS Power Good Delay from PGI to PGO
- * 75mS Delay for 3.3V, 5V and 12V Power Turn on
- * 2.8mS Delay for PSON Control to FPO Turn off
- * 38mS / 115mS PSON on/off De-Bounce Time
- * 73uS width Noise Deglitches
- * 73uS De-Bounce Time for UVP and OCP
- * Wide Supply Voltage Range

ORDERING INFORMATION

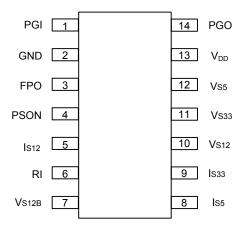
Ordering	Number	Dookogo	Dooking		
Lead Free Plating	Halogen Free	Package	Packing		
S3515L-D14-T	S3515G-D14-T	DIP-14	Tube		
S3515L-S14-R	S3515G-S14-R	SOP-14	Tape Reel		
S3515L-S14-T	S3515G-S14-T	SOP-14	Tube		





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■ PIN CONFIGURATION



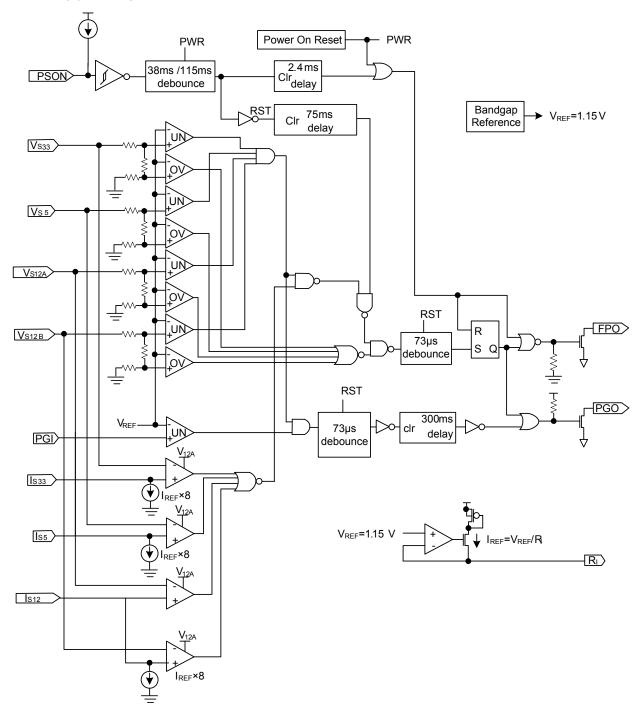
■ PIN DESCRIPTION

PIN NO	PIN NAME	TYPE	DESCRIPTION
1	PGI	input	Power good input.
3	FPO	output	Fault protection output, open drain output stage.
4	PSON	input	Power on/off control signal sends from CPU or main-board. The power supply will be turned on/off after 38mS/115mS respectively.
8	I _{S5}	input	5V over current protection.
9	I _{S33}	input	3.3V over current protection.
5	I _{S12}	input	12V over current protection. Regarding typical application, this pin is connected to the positive end of a current shunt through one resistor. When the voltage on IS12 is higher than that of VS12 by 5mV, OCP will be enabled. One current sink, 8 x I _{REF} , is used to determine the voltage drop between the positive end of the current shunt and VS12. Adjusting the value of the external resistor can adjust the threshold for OCP accordingly. The operation for IS5 or IS33 is the same.
6	RI	input	Current sense setting. An external resistor Ri is connected between RI pin and GND pin will adjust a reference current, I _{REF} = 1.15/Ri, for OCP function.
12	V_{S5}	input	5V over/under-voltage protection.
7	V_{S12B}	input	Second 12V over/under-voltage protection.
10	V_{S12}	input	12V over/under-voltage protection.
11	V_{S33}	input	3.3V over/under-voltage protection.
13	V_{DD}	power	Supply voltage. 4V ~ 15V.
14	PGO	output	Power good logic output, open drain output stage. The power good delay is 300mS from PGI to PGO.
2	GND	power	Ground.



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BLOCK DIAGRAM



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ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
DC Supply Voltage	V_{DD}	-0.3 ~ 16	V
Input Voltage (PSON, V _{S33} , V _{S5} , PGI)	V_{IN}	-0.3 ~ 8	V
Output Valtage (FDO)	V	-0.3 ~ 16	V
Output Voltage (FPO)	V _{OUT}	-0.3 ~ 8	V
Power Dissipation (PGO)	P _D	400	mW
Operating Temperature	T_OPR	-40 ~ +85	°C
Storage Temperature	T _{STG}	-55 ~ +1 50	°C

Note 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ RECOMMENDED OPERATING CONDITIONS

PARAMETER		SYMBOL	RATINGS	UNIT	
DC Supply Voltage		V_{DD}	4 ~ 15	V	
Input Voltage (PSON, V _{S33} , V _{S5} , I _{S33} , I _{S5} , PGI)		\/	7		
Input Voltage (V _{S12} ,V _{S12B} , I _{S12})		V _{IN}	15	V	
Output Voltage	FPO	Vout	15	V	
Output Voltage	PGO	Vout	7		
Output Sink Current	FPO		20	mA	
Output Sink Current	PGO	I _{O(SINK)}	10		
Supply Voltage Rising Time (Note)		t _R	1	mS	
Output Current RI		I _{RI}	12.5 ~ 62.5	μΑ	

Note V_{DD} rising and falling slew rate must be less than 14V/mS.

■ ELECTRICAL CHARACTERISTICS (V_{DD}=12V, T_A=25°C)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
UNDER-VOLTAGE AND PGI, PGO							
Input Threshold Voltage PGI		V_{PGI}		1.1	1.15	1.2	V
Under-voltage protect V _{S33}		1 01		2.6	2.8	3.0	
Under-voltage protect V _{S5}		V_{UVp}		4.0	4.2	4.4	V
Under-voltage protect V _{S12} , V _{S12B}				9.4	9.9	10.4	
Low Level Output Voltage (PGO)		V _{OL}	$V_{DD} = 12V I_{SINK} = 10mA$			0.7	V
Leakage Current (PGO)		I _{LEAK}	PGO = 5V			5	μA
Under-voltage Enable Delay Time				49	75	114	mS
Timing PG Delay PGI	to PGO	t _{PG}		200	300	450	mS
Noise Deglitch Time PGI	to PGO			150	250	350	μS
Timing UVP to Protection (FPO)		T_{UVP}	$V_{S33}, V_{S5}, V_{S12}, V_{S12B}$		73		μS
OVER-VOLTAGE AND OVER-CURRE	NT PRO	TECTION					
Over-Voltage Protection V _{S33}				3.7	3.9	4.1	
Over-Voltage Protection V _{S5}		V_{OVP}		5.7	6.1	6.5	V
Over-Voltage Protection V _{S12}	, V _{S12B}			13.2	13.8	14.4	
Ratio of Current Sense Sink Current to	Current		RI = $30 \text{ K}\Omega$,	7.6	8	8.4	
Sense Setting Pin (RI) Source Current		I _{REF}	0.1% Resistor	7.6	0	0.4	
Current Source Reference Voltage		V_{REF}		1.1	1.15	1.2	V
OCP Comparator Input Offset Voltage		$V_{I(OFF)}$	SR.	-5)		5	mV
Low Level Output Voltage (FPO)		V_{OL}	I _{SINK} =20mA	5.		0.7	V
Leakage Current (FPO)		I_{LEAK}	$V_{(FPO)} = 5V$			5	μA
Timing OVP to Protection		T _{OVP}	(DO)		73		μS
Timing OCP to Protection		TOCP	3 61/11.		73		μS
Timing OCP to Protection T _{OCP} 73 μS							

^{2.} Stresses above those listed may cause permanent damage to the device.

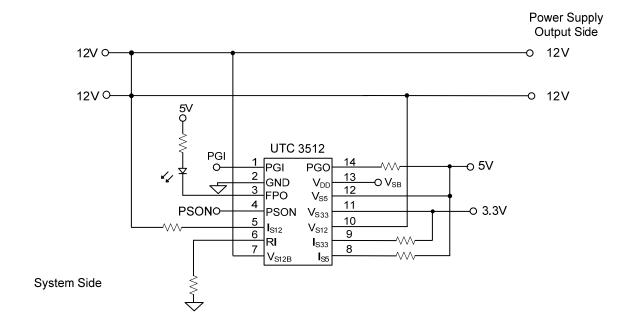
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ELECTRICAL CHARACTERISTICS(Cont.)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
PSON CONTROL							
High-Level Input Voltage		V _{IH}		1.9			V
Low-Level Input Voltage		V _{IL}				0.98	V
Timing PGO Low to FPO High		T _{PSOFF}		1.6	2.8	4.0	mS
Timing DCON to On/Off	ON	T _{PSON}		24	38	57	mS
Timing PSON to On/Off	OFF			24	38	57	mS
Input Pull-up Current		I _{PSON}	PSON = 0V		120		μA
TOTAL DEVICE							
Supply Current		I _{DD}	$PSON = 5V, V_{DD} = 5V$		1.0	1.8	mA
V _{DD} Start Threshold Voltage		V_{THD}				4.0	V
V _{DD} Min. Operation Voltage After Start-up		V_{MIN}		3.65			V

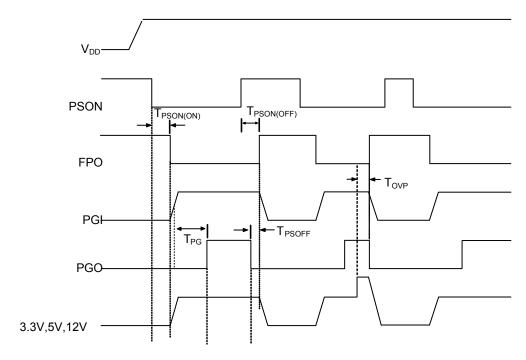


TYPICAL APPLICATION CIRCUIT

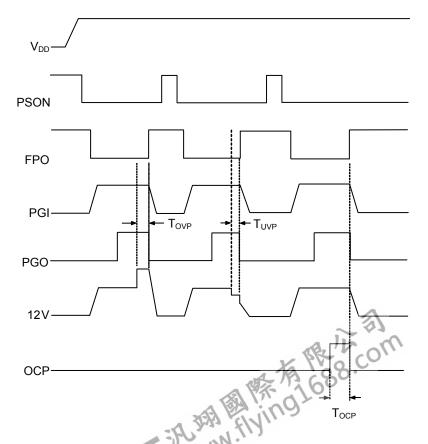


■ TIMING DIAGRAM

PSON On/Off and 3.3V, 5V,12V OVP Function



3.3V,5 V,12V OVP UVP and OCP Function



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